

1. FEATURES

- Low Offset Voltage: 10 μ V (max)
- Zero-Drift: 0.08 μ V/ $^{\circ}$ C
- Low Noise: 13nV/ $\sqrt{\text{Hz}}$
 - 0.1Hz to 10Hz Noise: 0.2 μ V_{PP}
- Excellent DC Precision:
 - PSRR: 148dB
 - CMRR: 150dB
 - Open-Loop Gain: 136dB
- Gain Bandwidth: 2.5MHz
- Quiescent Current: 600 μ A (typ)
- Wide Supply Range: \pm 2.25V to \pm 20V
- Rail-to-Rail Output
- Input Includes Negative Rail
- RFI Filtered Inputs
- 1/2 Channel

2. APPLICATIONS

- Bridge Amplifiers
- Strain Gauges
- Transducer Applications
- Temperature Measurement
- Electronic Scales
- Medical Instrumentation
- Resistance Temperature Detectors

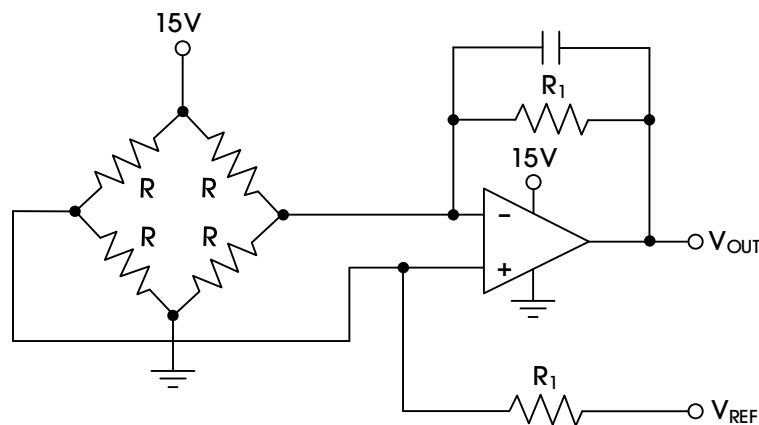
3. DESCRIPTION

The OPZ30x is a high-performance, general-purpose operational amplifiers that supports 4.5 - 40V supply range. With extremely low input offset voltage of 10 μ V (maximum) and a high CMRR of 150dB, the OPZ30x operational amplifiers provide excellent initial accuracy and rail-to-rail output. The devices work well with both single-supply convenient portable equipment and differential output scenarios.

The OPZ30x family provides up to 2.5MHz bandwidth, 3V/ μ s slew rate and outstanding DC performance, which is rather suitable for active filter circuits.

The OPZ30x operational amplifiers are offered in the SOT23-5, SOIC-8, and MSOP-8 packages. All versions are specified from -40 $^{\circ}$ C to 125 $^{\circ}$ C. See [Table 1](#) for the order information.

Bridge Amplifier



OPZ30x

40V, High-Performance, General-Purpose, Zero-Drift Operational Amplifiers

Table 1 lists the order information.

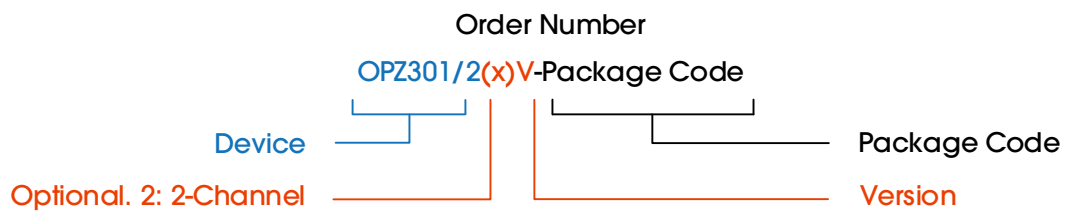
Table 1. Order Information

ORDER NUMBER ⁽¹⁾	PART NUMBER	CH (#)	PACKAGE	MARKING	I _Q PER CH (TYP) (μA)	GBW (MHz)	SLEW RATE (TYP)	OP TEMP (°C)	PKG OPTION
OPZ302ASOIC8	OPZ302	1	SOIC-8	OPZ302/AVWWW	450	2.5	3	-40 - 125	T/R-4000
OPZ302ASOT235	OPZ302	1	SOT23-5	OPZ302/AVWWW	450	2.5	3	-40 - 125	T/R-4000
OPZ302AMSOP8	OPZ302	1	MSOP-8	OPZ302/AVWWW	450	2.5	3	-40 - 125	T/R-4000
OPZ3022ASOIC8	OPZ3022	2	SOIC-8	OPZ3022/AVWWW	450	2.5	3	-40 - 125	T/R-4000
OPZ3022AMSOP-8	OPZ3022	2	SOIC-8	OPZ3022/AVWWW	450	2.5	3	-40 - 125	T/R-4000

Devices can be ordered via the following two ways:

1. Place orders directly on our website (www.analogyssemi.com), or;
2. Contact our sales team by mailing to sales@analogyssemi.com.

Note:



4. PIN CONFIGURATION AND FUNCTIONS

Figure 1 illustrates the pin configuration (1 CH Devices).

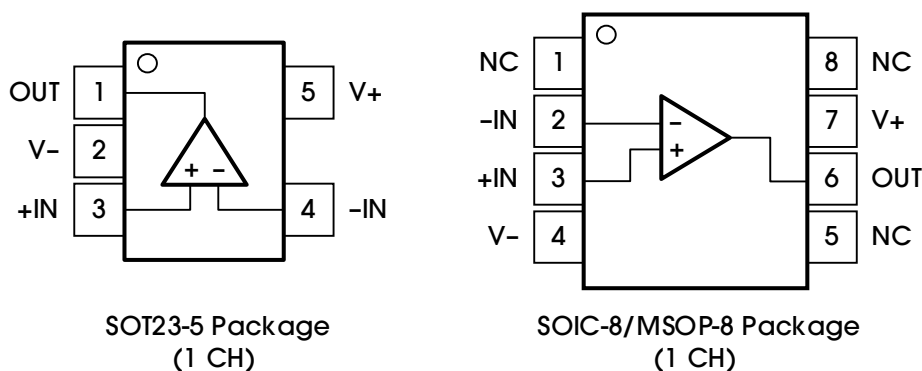


Figure 1. Pin Configuration (1 CH Devices)

Table 2 lists the pin functions (1 CH Devices).

Table 2. Pin Functions (1 CH Devices)

POSITION		NAME	TYPE	DESCRIPTION
SOT23-5	SOIC-8			
1	6	OUT	Output	Output
2	4	V-	Power	Negative (lowest) power supply
3	3	+IN	Input	Positive (non-inverting) input
4	2	-IN	Input	Negative (inverting) input
5	7	V+	Power	Positive (highest) power supply
—	1, 5, 8	NC	I/O	No internal connection (can be left floating)

Figure 2 illustrates the pin configuration (2 CH Devices).

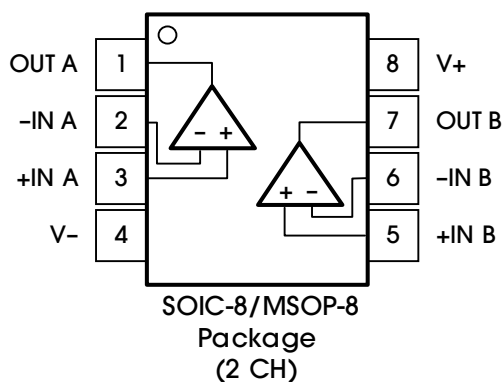


Figure 2. Pin Configuration (2 CH Devices)

Table 3 lists the pin functions (2 CH Devices).

Table 3. Pin Functions (2 CH Devices)

POSITION	NAME	TYPE	DESCRIPTION
1	OUT A	Output	Output, channel A
2	-IN A	Input	Inverting input, channel A
3	+IN A	Input	Non-inverting input, channel A
4	V-	Power	Negative (lowest) power supply
5	+IN B	Input	Non-inverting input, channel B
6	-IN B	Input	Inverting input, channel B
7	OUT B	Output	Output, channel B
8	V+	Power	Positive (highest) power supply

5. SPECIFICATIONS

5.1 ABSOLUTE MAXIMUM RATINGS

Table 5 lists the absolute maximum ratings of the OPZ30x. Over operating free-air temperature range, unless otherwise noted.

Table 4. Absolute Maximum Ratings

PARAMETER	DESCRIPTION		MIN	MAX	UNITS
Voltage	Supply	Split	±2.25	±20	V
		Single	4.5	40	
	Signal input pins ⁽²⁾	Common-mode	(V-) - 0.5	(V+) + 0.5	
		Differential		±0.7	
Current	Signal input pins			±10	mA
	Output short-circuit ⁽³⁾	Continuous			
Temperature	Operating, T _A ⁽⁴⁾		-55	150	°C
	Junction, T _J			150	
	Storage, T _{stg}		-65	150	

Note 1: Stresses beyond those listed under Table 5 may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Table 7. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

Note 2: Input terminals are diode-clamped to the power-supply rails. Input signals that can swing more than 0.5V beyond the supply rails should be current-limited to 10mA or less.

Note 3: Short-circuit to ground, V-, or V+.

Note 4: Provided device does not exceed maximum junction temperature (T_J) at any time.

5.2 ESD RATINGS

Table 6 lists the ESD ratings of the OPZ30x.

Table 5. ESD Ratings

PARAMETER	SYMBOL	DESCRIPTION	VALUE	UNITS
Electrostatic Discharge	V _(ESD)	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	TBD	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	TBD	

Note 1: The JEDEC document JEP155 indicates that 500V HBM allows safe manufacturing with a standard ESD control process.

Note 2: The JEDEC document JEP157 indicates that 250V CDM allows safe manufacturing with a standard ESD control process.

5.3 RECOMMENDED OPERATING CONDITIONS

Table 7 lists the recommended operating conditions for the OPZ30x. Over operating free-air temperature range, unless otherwise noted.

Table 6. Recommended Operating Conditions

PARAMETER	DESCRIPTION	MIN	NOM	MAX	UNITS
Operating Voltage Range	Split supply	±2.25		±20	V
	Single supply	4.5		40	V
Specified Temperature Range		-40		125	°C

5.4 THERMAL INFORMATION

Table 8 lists the thermal information for the OPZ30x.

Table 7. Thermal Information

PARAMETER	SYMBOL	SOT23-5	SOIC-8	UNITS
Junction-to-Ambient Thermal Resistance	$R_{\theta JA}$	168	150	°C/W
Junction-to-Case (Top) Thermal Resistance	$R_{\theta JC(top)}$	103	54	°C/W
Junction-to-Board Thermal Resistance	$R_{\theta JB}$	39	90	°C/W
Junction-to-Top Characterization Parameter	ψ_{JT}	10	3	°C/W
Junction-to-Board Characterization Parameter	ψ_{JB}	36	86	°C/W
Junction-to-Case (Bottom) Thermal Resistance	$R_{\theta JC(bot)}$	66	90	°C/W

5.5 ELECTRICAL CHARACTERISTICS (OPZ30X)

5.5.1 HIGH-VOLTAGE OPERATION

Table 9 lists the electrical characteristics of the OPZ30X for high-voltage operation. $T_A = 25^\circ\text{C}$, $V_S = \pm 4\text{V}$ to $\pm 20\text{V}$ ($V_S = 8\text{V}$ to 40V), $R_L = 10\text{k}\Omega$ connected to $V_S / 2$, and $V_{CM} = V_{OUT} = V_S / 2$, unless otherwise noted.

Table 8. Electrical Characteristics (High-Voltage Operation)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
OFFSET VOLTAGE						
Input Offset Voltage	V_{OS}			± 1	± 10	μV
		$T_A = -40^\circ\text{C}$ to 125°C		± 0.01	± 0.08	$\mu\text{V}/^\circ\text{C}$
Power-Supply Rejection Ratio	PSRR	$V_S = 4\text{V}$ to 40V , $T_A = -40^\circ\text{C}$ to 125°C		± 0.04	± 0.36	$\mu\text{V}/\text{V}$
Long-Term Stability ⁽²⁾				4		μV
INPUT BIAS CURRENT						
Input Bias Current	I_B	$V_{CM} = V_S / 2$		± 300	± 1000	pA
		$T_A = -40^\circ\text{C}$ to 125°C			± 10	nA
Input Offset Current	I_{OS}			± 400	± 2000	pA
		$T_A = -40^\circ\text{C}$ to 125°C			± 6	nA
NOISE						
Input Voltage Noise	e_n	$f = 0.1\text{Hz}$ to 10Hz		200		nV_{PP}
		$f = 0.1\text{Hz}$ to 10Hz		30		nV_{RMS}
Input Voltage Noise Density		$f = 1\text{kHz}$		13		$\text{nV}/\sqrt{\text{Hz}}$
Input Current Noise Density	i_n	$f = 1\text{kHz}$		7		$\text{fA}/\sqrt{\text{Hz}}$
INPUT VOLTAGE RANGE						
Common-Mode Voltage Range	V_{CM}	$T_A = -40^\circ\text{C}$ to 125°C	V-		$(V_+) - 1.5$	V
Common-Mode Rejection Ratio	CMRR	$(V_-) < V_{CM} < (V_+) - 1.5\text{V}$	TBD	145		dB
		$(V_-) + 0.5\text{V} < V_{CM} < (V_+) - 1.5\text{V}$, $V_S = \pm 20\text{V}$	TBD	150		dB
		$(V_-) + 0.5\text{V} < V_{CM} < (V_+) - 1.5\text{V}$, $V_S = \pm 20\text{V}$, $T_A = -40^\circ\text{C}$ to 125°C	TBD	150		dB
INPUT IMPEDANCE						
Differential	Z_{ID}			100 6		$\text{M}\Omega$ pF
Common-Mode	Z_{IC}			6 9.5		$10^{12}\Omega$ pF
OPEN-LOOP GAIN						
Open-Loop Voltage Gain	A_{OL}	$(V_-) + 0.5\text{V} < V_O < (V_+) - 0.5\text{V}$	TBD	136		dB
		$(V_-) + 0.5\text{V} < V_O < (V_+) - 0.5\text{V}$, $T_A = -40^\circ\text{C}$ to 125°C	TBD	126		dB
FREQUENCY RESPONSE						
Gain-Bandwidth Product	GBW	OPZ302		2.5		MHz
Slew Rate	SR	$G = 1$, OPZ302		3		$\text{V}/\mu\text{s}$
Settling Time	0.1%	t_s	$V_S = \pm 20\text{V}$, $G = 1$, 10V step	20		μs
	0.01%		$V_S = \pm 20\text{V}$, $G = 1$, 10V step	27		μs
Overload Recovery Time	t_{OR}	$V_{IN} \times G = V_S$		1		μs
Total Harmonic Distortion + Noise	THD+N	1kHz, $G = 1$, $V_{OUT} = 1\text{V}_{RMS}$		0.0001%		

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
OUTPUT						
Voltage Output Swing from Rail		No load		6	15	mV
		$R_L = 10k\Omega$		100	150	mV
		$T_A = -40^\circ\text{C to } 125^\circ\text{C}$		TBD	200	mV
Short-Circuit Current	I_{SC}	Sinking		-20		mA
		Sourcing		29		mA
Open-Loop Output Resistance	R_O	$f = 1\text{MHz}, I_O = 0$		120		Ω
Capacitive Load Drive	C_{LOAD}			2		nF
POWER SUPPLY						
		$V_S = \pm 4\text{V to } V_S = \pm 20\text{V}$		600	TBD	
		$I_O = 0\text{mA}, T_A = -40^\circ\text{C to } 125^\circ\text{C}$			TBD	μA

Note 1: $V_S / 2 = \text{mid-supply}$.

Note 2: 1000-hour life test at 125°C demonstrated randomly distributed variation in the range of measurement limits—approximately $4\mu\text{V}$.

5.5.2 LOW VOLTAGE OPERATION

Table 10 lists the electrical characteristics of the OPZ30X for low-voltage operation. $T_A = 25^\circ\text{C}$, $V_S = \pm 2.25\text{V}$ to $< \pm 4\text{V}$ ($V_S = 4.5\text{V}$ to $< 8\text{V}$), $R_L = 10\text{k}\Omega$ connected to $V_S / 2$, and $V_{CM} = V_{OUT} = V_S / 2$, unless otherwise noted.

Table 9. Electrical Characteristics (Low-Voltage Operation)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
OFFSET VOLTAGE						
Input Offset Voltage	V_{OS}	$T_A = -40^\circ\text{C}$ to 125°C		± 1 ± 0.01	± 10 ± 0.08	μV $\mu\text{V}/^\circ\text{C}$
Power-Supply Rejection Ratio	PSRR	$V_S = 4.5\text{V}$ to 40V , $T_A = -40^\circ\text{C}$ to 125°C		± 0.04	± 0.36	$\mu\text{V}/\text{V}$
Long-Term Stability ⁽²⁾				4		μV
INPUT BIAS CURRENT						
Input Bias Current	I_B	$T_A = -40^\circ\text{C}$ to 125°C		± 300	± 1000 ± 10	pA nA
Input Offset Current	I_{OS}	$T_A = -40^\circ\text{C}$ to 125°C		± 400	± 2000 ± 6	pA nA
NOISE						
Input Voltage Noise	e_n	$f = 0.1\text{Hz}$ to 10Hz $f = 0.1\text{Hz}$ to 10Hz		200 30		nV_{P-P} nV_{RMS}
Input Voltage Noise Density		$f = 1\text{kHz}$		13		$\text{nV}/\sqrt{\text{Hz}}$
Input Current Noise Density	i_n	$f = 1\text{kHz}$		7		$\text{fA}/\sqrt{\text{Hz}}$
INPUT VOLTAGE RANGE						
Common-Mode Voltage Range	V_{CM}	$T_A = -40^\circ\text{C}$ to 125°C	V-		$(V+) - 1.5$	V
Common-Mode Rejection Ratio	CMRR	$(V-) < V_{CM} < (V+) - 1.5\text{V}$	TBD	125		dB
		$(V-) + 0.5\text{V} < V_{CM} < (V+) - 1.5\text{V}$, $V_S = \pm 2\text{V}$	TBD	130		dB
		$(V-) + 0.5\text{V} < V_{CM} < (V+) - 1.5\text{V}$, $V_S = \pm 2\text{V}$, $T_A = -40^\circ\text{C}$ to 125°C	TBD	130		dB
INPUT IMPEDANCE						
Differential	Z_{ID}			100 6		$\text{M}\Omega$ pF
Common-Mode	Z_{IC}			6 9.5		$10^{12}\Omega$ pF
OPEN-LOOP GAIN						
Open-Loop Voltage Gain	A_{OL}	$(V-) + 0.5\text{V} < V_O < (V+) - 0.5\text{V}$, $R_L = 5\text{k}\Omega$	TBD	120		dB
		$(V-) + 0.5\text{V} < V_O < (V+) - 0.5\text{V}$	TBD	130		dB
		$(V-) + 0.5\text{V} < V_O < (V+) - 0.5\text{V}$, $T_A = -40^\circ\text{C}$ to 125°C	TBD	120		dB
FREQUENCY RESPONSE						
Gain-Bandwidth Product	GBW	OPZ302		2.5		MHz
Slew Rate	SR	$G = 1$, OPZ302		3		$\text{V}/\mu\text{s}$
Overload Recovery Time	t_{OR}	$V_{IN} \times G = V_S$		1		μs
Total Harmonic Distortion + Noise	THD+N	1kHz, $G = 1$, $V_{OUT} = 1\text{V}_{RMS}$		0.0001%		

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
OUTPUT						
Voltage Output Swing from Rail		No load		6	15	mV
		$R_L = 10k\Omega$		100	150	mV
		$T_A = -40^\circ\text{C to } 125^\circ\text{C}$		TBD	200	mV
Short-Circuit Current	I_{SC}	Sinking		-20		mA
		Sourcing		29		mA
Open-Loop Output Resistance	R_O	$f = 1\text{MHz}, I_O = 0$		120		Ω
Capacitive Load Drive	C_{LOAD}			2		nF
POWER SUPPLY						
		$V_S = \pm 2.25\text{V to } V_S = \pm 4\text{V}$		595	TBD	
		$I_O = 0\text{mA}, T_A = -40^\circ\text{C to } 125^\circ\text{C}$			TBD	μA

Note 1: $V_S / 2 = \text{mid-supply}$.

Note 2: 1000-hour life test at 125°C demonstrated randomly distributed variation in the range of measurement limits—approximately $4\mu\text{V}$.

6. PACKAGE INFORMATION

The OPZ30x family is available in the SOT23-5, SOIC-8, MSOP-8, and TSSOP-14 packages.

6.1 SOT23-5 PACKAGE

Figure 55 shows the SOT23-5 package view.

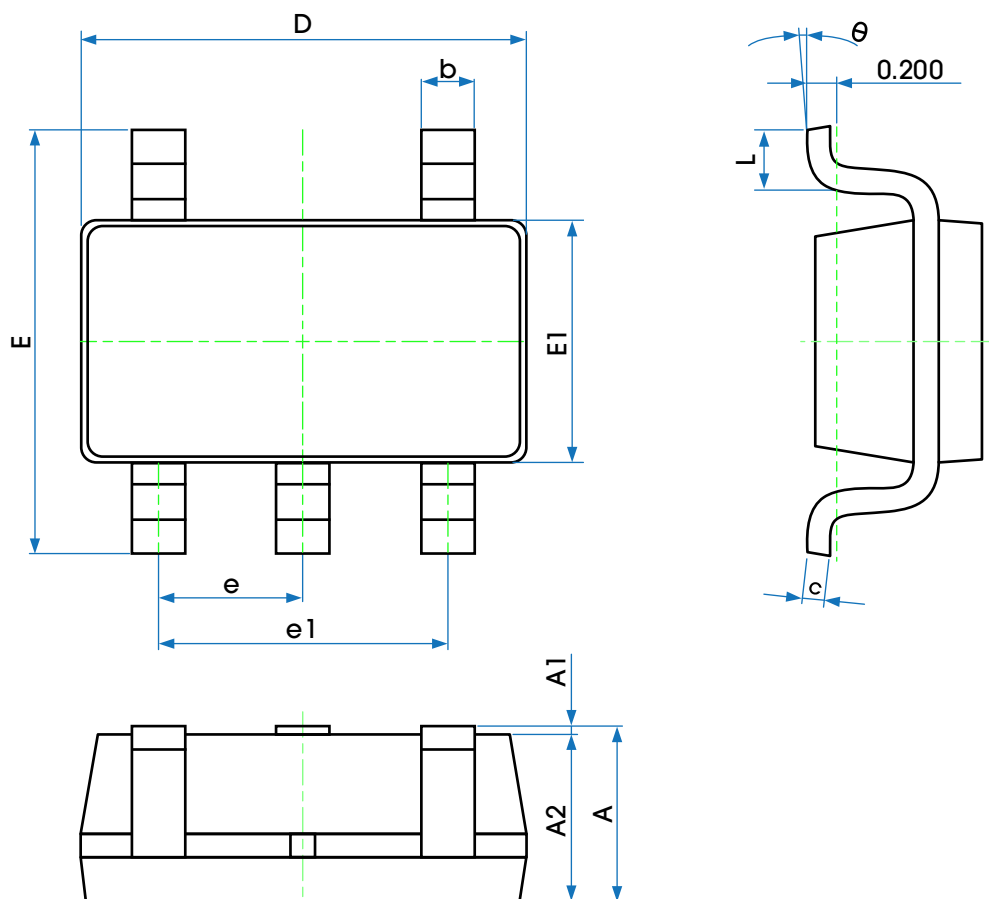


Figure 3. SOT23-5 Package View

Table 13 provides detailed information about the dimensions of the SOT23-5 package.

Table 10. Dimensions of the SOT23-5 Package

SYMBOL	DIMENSIONS IN MILLIMETERS		DIMENSIONS IN INCHES	
	MIN	MAX	MIN	MAX
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	2.650	2.950	0.104	0.116
E1	1.500	1.700	0.059	0.067
e	0.950 (BSC)		0.037 (BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

6.2 SOIC-8 PACKAGE

Figure 56 shows the SOIC-8 package view.

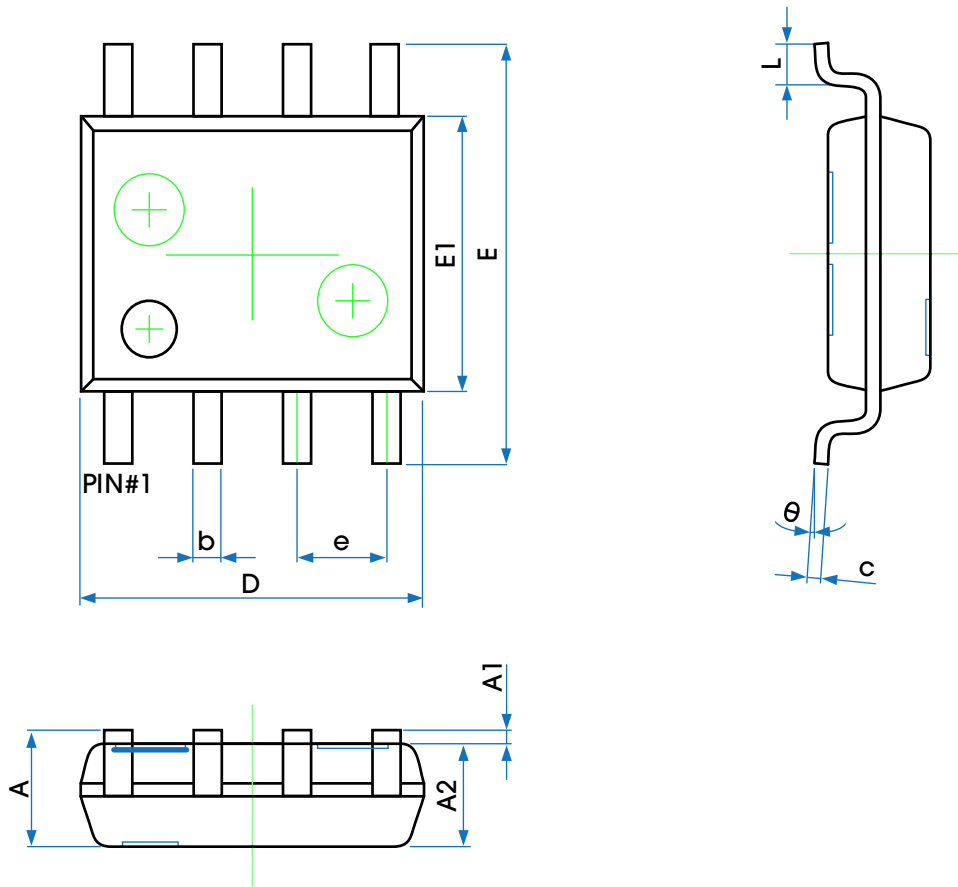


Figure 4. SOIC-8 Package View

Table 14 provides detailed information about the dimensions of the SOIC-8 package.

Table 11. Dimensions of the SOIC-8 Package

SYMBOL	DIMENSIONS IN MILLIMETERS		DIMENSIONS IN INCHES	
	MIN	MAX	MIN	MAX
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.007	0.010
D	4.700	5.100	0.185	0.201
E	5.800	6.200	0.228	0.244
E1	3.800	4.000	0.150	0.157
e	1.270 (BSC)		0.050 (BSC)	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

TAPE AND REEL INFORMATION

TBD

REVISION HISTORY

REVISION	DATE	DESCRIPTION
Rel 0.1	15 January 2021	DRAFT.
Rel 0.5.1	21 December 2021	<ol style="list-style-type: none"> 1. Updated the paragraph after the Order Information table. 2. Added the THERMAL INFORMATION section. 3. Added the TYPICAL CHARACTERISTICS section. 4. Added the DETAILED DESCRIPTION section. 5. Added the APPLICATION AND IMPLEMENTATION section. 6. Added the POWER SUPPLY RECOMMENDATIONS section. 7. Added the LAYOUT section.
Rel 0.5.2	27 January 2022	<ol style="list-style-type: none"> 1. Removed information about the 4-channel. 2. Updated Table 5. 3. Updated Section 5.5. 4. Updated Section 7.2. 5. Updated the first paragraph in Section 8. 6. Updated "18V" and "36V" to "20V" and "40V". 7. Updated the Order Information table.
Rel 0.8	27 June 2022	<ol style="list-style-type: none"> 1. Update key specifications in Section 5
Rel 0.8.1	6 July 2022	<ol style="list-style-type: none"> 1. Update key specifications in Section 5, ESD and delete OPZ301 info